NSN 5961-01-025-9327

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-025-9327 **Inclosure Material:** Plastic **Overall Length:** 0.725 inches **Overall Height:** 0.170 inches **Overall Width:** 0.250 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 15.0 collector to emitter voltage/static/base open all transistor **Current Rating Per Characteristic:** 0.50 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector absolute all transistor **Capacitance Rating In Picofarads:** 4.0 all transistor **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0